5V ECL Error Detection/ Correction Circuit

The MC10E/100E193 is an error detection and correction (EDAC) circuit. Modified Hamming parity codes are generated on an 8-bit word according to the pattern shown in the logic symbol. The P5 output gives the parity of the whole word. The word parity is also provided at the PGEN pin, after Odd/Even parity control and gating with the BPAR input. This output also feeds to a 1-bit shiftable register, for use as part of a scan ring.

Used in conjunction with 12-bit parity generators such as the E160, a SECDED (single error correction, double error detection) error system can be designed for a multiple of an 8-bit word.

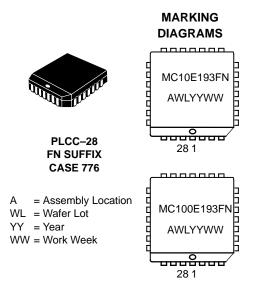
The 100 Series contains temperature compensation.

- Hamming Code Generation
- 8-Bit Word, Expandable
- Provides Parity of Whole Word
- Scannable Parity Register
- PECL Mode Operating Range: V_{CC} = 4.2 V to 5.7 V with V_{EE} = 0 V
- NECL Mode Operating Range: $V_{CC}=0$ V with $V_{EE}=-4.2$ V to -5.7 V
- Internal Input Pulldown Resistors
- ESD Protection: >1 KV HBM, >75 V MM
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 368 devices



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ORDERING INFORMATION

Device	Package	Shipping
MC10E193FN	PLCC-28	37 Units/Rail
MC10E193FNR2	PLCC-28	500 Units/Reel
MC100E193FN	PLCC-28	37 Units/Rail
MC100E193FNR2	PLCC-28	500 Units/Reel

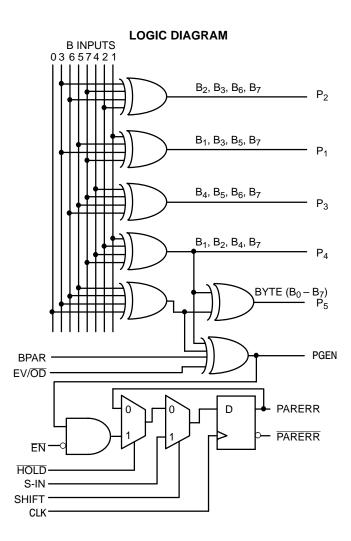
EN HOLD S-IN SHIFT CLK V_{CCO} PGEN \Box 25 23 22 21 20 19 24 EV/OD 26 18 PARERR 17 PARERR BPAR 27 B₀ 28 16 🗌 V_{CC} 0 15 🗌 P₅ V_{EE} **Pinout: 28-Lead PLCC** (Top View) 14 🗌 V_{CCO} B₁ 2 B₂ 13 🗌 P₄ 3 B₃ 4 12 🛛 P₃ B_5 B_6 B₇ B_4 P_1 V_{CCO} P_2 * All V_{CC} and V_{CCO} pins are tied together on the die.

LOGIC DIAGRAM AND PINOUT ASSIGNMENT

Warning: All V_{CC} , V_{CCO} , and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

PIN DESCRIPTION

PIN	FUNCTION
B0–B6	ECL Bit Inputs
P1–P5	ECL Parity Outputs
PARERR, PARERR	ECL Parity Error Outputs
PGEN	ECL Word Parity Generator Output
CLK	ECL Clock Input
SHIFT	ECL Shift Input (Active-High)
S–IN	ECL Serial Data Input
HOLD	ECL Hold (Active–Low)
EN	ECL Enable (Active–Low)
EV/DD	ECL Even/Odd Contact
BPAR	ECL Bit Parity Gate Input
V _{CC} , V _{CCO}	Positive Supply
V _{EE}	Negative Supply
NC	No Connect



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MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	$V_{EE} = 0 V$		8	V
V_{EE}	NECL Mode Power Supply	$V_{CC} = 0 V$		-8	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{c} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 6	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
ТА	Operating Temperature Range			0 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	28 PLCC 28 PLCC	63.5 43.5	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	28 PLCC	22 to 26	°C/W
V_{EE}	PECL Operating Range NECL Operating Range			4.2 to 5.7 -5.7 to -4.2	V V
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

10E SERIES PECL DC CHARACTERISTICS V_{CCx} = 5.0 V; V_{EE} = 0.0 V (Note 1.)

		O°C			25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		112	134		112	134		112	134	mA
V _{OH}	Output HIGH Voltage (Note 2.)	3980	4070	4160	4020	4105	4190	4090	4185	4280	mV
V _{OL}	Output LOW Voltage (Note 2.)	3050	3210	3370	3050	3210	3370	3050	3227	3405	mV
V _{IH}	Input HIGH Voltage	3830	3995	4160	3870	4030	4190	3940	4110	4280	mV
VIL	Input LOW Voltage	3050	3285	3520	3050	3285	3520	3050	3302	3555	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.3	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC}. $\rm V_{EE}$ can vary +0.46 V / –0.06 V.

2. Outputs are terminated through a 50 ohm resistor to V_{CC} -2 volts.

10E SERIES NECL DC CHARACTERISTICS V_{CCx}= 0.0 V; V_{EE}= -5.0 V (Note 1.)

		0°C			25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		112	134		112	134		112	134	mA
V _{OH}	Output HIGH Voltage (Note 2.)	-1020	-930	-840	-980	-895	-810	-910	-815	-720	mV
V _{OL}	Output LOW Voltage (Note 2.)	-1950	-1790	-1630	-1950	-1790	-1630	-1950	-1773	-1595	mV
VIH	Input HIGH Voltage	-1170	-1005	-840	-1130	-970	-810	-1060	-890	-720	mV
VIL	Input LOW Voltage	-1950	-1715	-1480	-1950	-1715	-1480	-1950	-1698	-1445	mV
I _{IH}	Input HIGH Current			150			150			150	μA
IIL	Input LOW Current	0.5	0.3		0.5	0.065		0.3	0.2		μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC}. $\rm V_{EE}$ can vary +0.46 V / –0.06 V.

2. Outputs are terminated through a 50 ohm resistor to $V_{\mbox{CC}}\mbox{--}2$ volts.

100E SERIES PECL DC CHARACTERISTICS V_{CCx}= 5.0 V; V_{EE}= 0.0 V (Note 1.)

		0°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		112	134		112	134		129	155	mA
V _{OH}	Output HIGH Voltage (Note 2.)	3975	4050	4120	3975	4050	4120	3975	4050	4120	mV
V _{OL}	Output LOW Voltage (Note 2.)	3190	3295	3380	3190	3255	3380	3190	3260	3380	mV
V _{IH}	Input HIGH Voltage	3835	4050	4120	3835	4120	4120	3835	4120	4120	mV
V _{IL}	Input LOW Voltage	3190	3300	3525	3190	3525	3525	3190	3525	3525	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The Device and accigned to most the De opermeters of the main and above table, and the most and equilibrium has been extended and transverse air flow greater than 500 lfpm is maintained.
 Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.46 V / -0.8 V.

2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

100E SERIES NECL DC CHARACTERISTICS V_{CCx} = 0.0 V; V_{EE} = -5.0 V (Note 1.)

		0°C		25°C							
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		112	134		112	134		129	155	mA
V _{OH}	Output HIGH Voltage (Note 2.)	-1025	-950	-880	-1025	-950	-880	-1025	-950	-880	mV
V _{OL}	Output LOW Voltage (Note 2.)	-1810	-1705	-1620	-1810	-1745	-1620	-1810	-1740	-1620	mV
V _{IH}	Input HIGH Voltage	-1165	-950	-880	-1165	-880	-880	-1165	-880	-880	mV
V _{IL}	Input LOW Voltage	-1810	-1700	-1475	-1810	-1475	-1475	-1810	-1475	-1475	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current	0.5	0.3		0.5	0.25		0.5	0.2		μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained. 1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.46 V / -0.8 V.

2. Outputs are terminated through a 50 ohm resistor to V_{CC} -2 volts.

			0°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{MAX}	Maximum Toggle Frequency		TBD			TBD			TBD		GHz
t _{PLH}	Propagation Delay to Output										ps
t _{PHL}	B to P1, P2, P3, P4	350	700	1000	350	700	1000	350	700	1000	
	B to P5	400	775	1150	400	775	1150	400	775	1150	
	EV/OD, BPAR to PGEN	350	650	850	350	650	850	350	650	850	
	B to PGEN	600	1000	1450	600	1000	1450	600	1000	1450	
	CLK to PARERR	300	550	850	300	550	850	300	550	850	
ts	Setup Time										ps
	SHIFT	400	150		400	150		400	150		
	S-IN	300	50		300	50		300	50		
	HOLD	750	350		750	350		750	350		
	EN	500	250		500	250		500	250		
	EV/OD	1300	850		1300	850		1300	850		
	BPAR	1300	850		1300	850		1300	850		
	В	1700	1100		1700	1100		1700	1100		
t _h	Hold Time										ps
	SHIFT	200	-150		200	-150		200	-150		
	S-IN	300	- 50		300	- 50		300	- 50		
	HOLD	100	- 350		100	- 350		100	- 350		
	EN	100	- 250		100	- 250		100	- 250		
	EV/OD	- 200	- 850		- 200	- 850		- 200	- 850		
	BPAR	- 200	- 850		- 200	- 850		- 200	- 850		
	В	- 300	-1100		- 300	-1100		- 300	-1100		
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t _r	Rise/Fall Times										ps
t _f	(20 - 80%)	300	700	1100	300	700	1100	300	700	1100	

AC CHARACTERISTICS $~V_{CCx}\text{=}~5.0~V;~V_{EE}\text{=}~0.0~V~~\text{or}~~V_{CCx}\text{=}~0.0~V;~V_{EE}\text{=}~-5.0~V~(Note~1.)$

1. 10 Series: V_{EE} can vary +0.46 V / -0.06 V. 100 Series: V_{EE} can vary +0.46 V / -0.8 V.

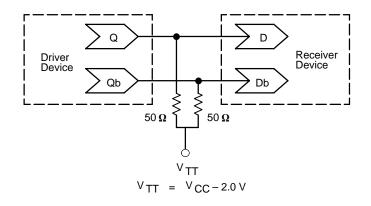
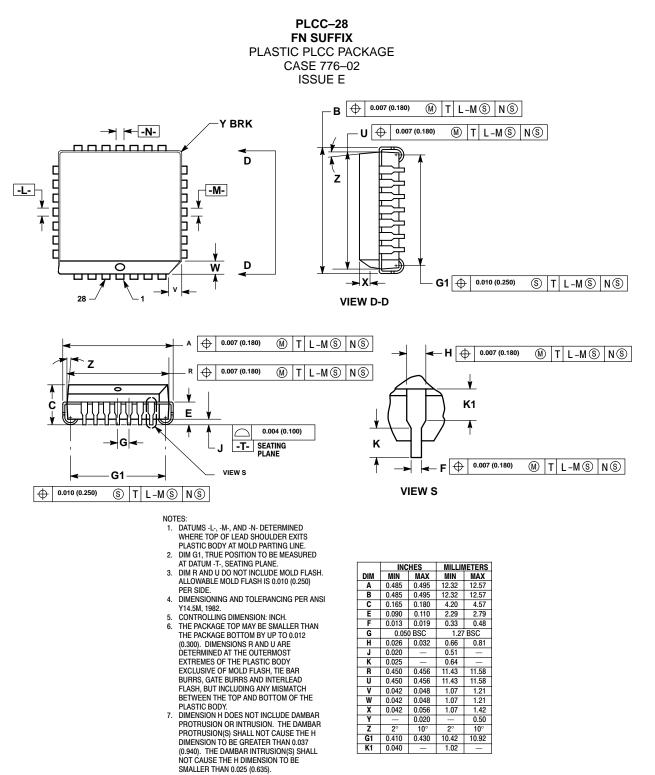


Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404	 ECLinPS Circuit Performance at Non–Standard V_{IH} Levels 	
AN1405	 ECL Clock Distribution Techniques 	
AN1406	 Designing with PECL (ECL at +5.0 V) 	
AN1503	 ECLinPS I/O SPICE Modeling Kit 	
AN1504	 Metastability and the ECLinPS Family 	
AN1568	 Interfacing Between LVDS and ECL 	
AN1596	 ECLinPS Lite Translator ELT Family SPICE I/O Model Kit 	
AN1650	 Using Wire–OR Ties in ECLinPS Designs 	
AN1672	 The ECL Translator Guide 	
AND8001	 Odd Number Counters Design 	
AND8002	 Marking and Date Codes 	
AND8020	 Termination of ECL Logic Devices 	

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